

# isc P-Channel MOSFET Transistor

# RSJ250P10

## • FEATURES

- Drain Current –I<sub>D</sub>= -25A@ T<sub>C</sub>=25℃
- Drain Source Voltage
  - : V<sub>DSS</sub>= -100V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 63m \Omega (Max) @V_{GS}=10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## DESCRITION

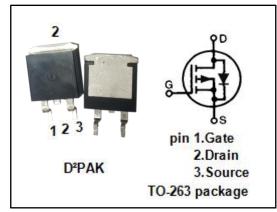
 Be suitable for synchronous rectification for server and general purpose applications

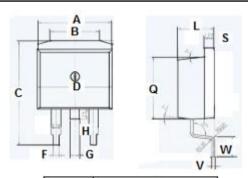
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
$V_{DSS}$	Drain-Source Voltage	-100	٧	
V <sub>G</sub> s	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current-Continuous	-25	Α	
I <sub>DM</sub>	Drain Current-Single Pulsed	-50	Α	
P <sub>D</sub>	Total Dissipation @Tc=25℃	50	W	
Tj	Max. Operating Junction Temperature	-55~150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$	

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	2.5	°C/W





DIM	m	m
IVIIU	MIN	MAX
Α	9.8	10.2
В	6.6	6.8
C	15.1	15.3
D	9.6	10
F	0.7	0.9
G	1.26	1.3
Н	1.2	1.45
L	4.4	4.6
Q	9.2	9.3
S	1.25	1.35
V	0.4	0.6
W	2.6	2.8



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### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = -1mA	-100		V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; ID = -1mA	-1.0	-2.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = -10V; I <sub>D</sub> = -25A V <sub>GS</sub> = -4.0V; I <sub>D</sub> = -12.5A		63 70	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0V		±10	uA
I <sub>D</sub> ss	Drain-Source Leakage Current	V <sub>DS</sub> = -100V; V <sub>GS</sub> = 0V		-1.0	μА
$V_{\text{SD}}$	Diode forward voltage	Is= -25A; V <sub>GS</sub> = 0V		-1.2	V

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